

NTD14N03R, NVD14N03R

Power MOSFET

14 A, 25 V, N-Channel DPAK

Features

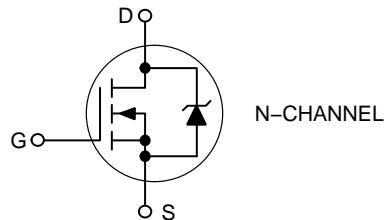
- Planar HD3e Process for Fast Switching Performance
- Low $R_{DS(on)}$ to Minimize Conduction Loss
- Low C_{iss} to Minimize Driver Loss
- Low Gate Charge
- Optimized for High Side Switching Requirements in High-Efficiency DC-DC Converters
- NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant



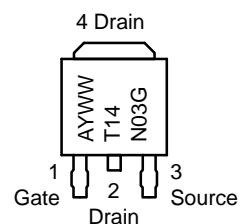
ON Semiconductor®

<http://onsemi.com>

14 AMPERES, 25 VOLTS
 $R_{DS(on)} = 70.4 \text{ m}\Omega \text{ (Typ)}$



MARKING DIAGRAM & PIN ASSIGNMENTS



A = Assembly Location*
Y = Year
WW = Work Week
14N03 = Device Code
G = Pb-Free Package

* The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package, the front side assembly code may be blank.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

NTD14N03R, NVD14N03R

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Drain-to-Source Breakdown Voltage (Note 3) ($V_{GS} = 0 \text{ Vdc}$, $I_D = 250 \mu\text{Adc}$) Temperature Coefficient (Positive)	$V(\text{br})_{\text{DSS}}$	25 –	28 –	– –	Vdc $\text{mV}/^\circ\text{C}$
Zero Gate Voltage Drain Current ($V_{DS} = 20 \text{ Vdc}$, $V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 20 \text{ Vdc}$, $V_{GS} = 0 \text{ Vdc}$, $T_J = 150^\circ\text{C}$)	I_{DSS}	– –	– –	1.0 10	μAdc
Gate-Body Leakage Current ($V_{GS} = \pm 20 \text{ Vdc}$, $V_{DS} = 0 \text{ Vdc}$)	I_{GSS}	–	–	± 100	nAdc
ON CHARACTERISTICS (Note 3)					
Gate Threshold Voltage (Note 3) ($V_{DS} = V_{GS}$, $I_D = 250 \mu\text{Adc}$) Threshold Temperature Coefficient (Negative)	$V_{GS(\text{th})}$	1.0 –	1.5 –	2.0 –	Vdc $\text{mV}/^\circ\text{C}$
Static Drain-to-Source On-Resistance (Note 3) ($V_{GS} = 4.5 \text{ Vdc}$, $I_D = 5 \text{ Adc}$) ($V_{GS} = 10 \text{ Vdc}$, $I_D = 5 \text{ Adc}$)	$R_{DS(\text{on})}$	– –	117 70.4	130 95	$\text{m}\Omega$
Forward Transconductance (Note 3) ($V_{DS} = 10 \text{ Vdc}$, $I_D = 5 \text{ Adc}$)	g_{FS}	–	7.0	–	Mhos
DYNAMIC CHARACTERISTICS					
Input Capacitance	$(V_{DS} = 20 \text{ Vdc}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz})$	C_{iss}	–	115	–
Output Capacitance		C_{oss}	–	62	–
Transfer Capacitance		C_{rss}	–	33	–
SWITCHING CHARACTERISTICS (Note 4)					
Turn-On Delay Time	$(V_{GS} = 10 \text{ Vdc}, V_{DD} = 10 \text{ Vdc}, I_D = 5 \text{ Adc}, R_G = 3 \Omega)$	$t_{d(\text{on})}$	–	3.8	–
Rise Time		t_r	–	27	–
Turn-Off Delay Time		$t_{d(\text{off})}$	–	9.6	–
Fall Time		t_f	–	2.0	–
Gate Charge	$(V_{GS} = 5 \text{ Vdc}, I_D = 5 \text{ Adc}, V_{DS} = 10 \text{ Vdc})$ (Note 3)	Q_T	–	1.8	–
		Q_1	–	0.8	–
		Q_2	–	0.7	–
SOURCE-DRAIN DIODE CHARACTERISTICS					
Forward On-Voltage	$(I_S = 5 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$ (Note 3) $(I_S = 5 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^\circ\text{C})$	V_{SD}	– –	0.93 0.82	1.2 –
Reverse Recovery Time		t_{rr}	–	6.6	–
		t_a	–	4.75	–
Reverse Recovery Stored Charge		t_b	–	1.88	–
	Q_{RR}	–	0.002	–	μC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$.

4. Switching characteristics are independent of operating junction temperatures.

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TYPICAL CHARACTERISTICS

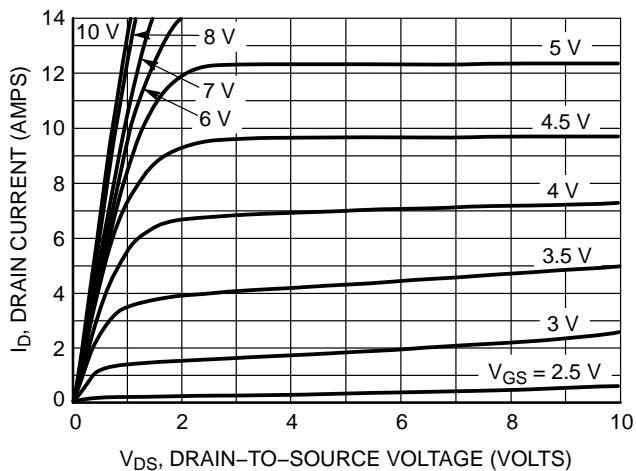


Figure 1. On-Region Characteristics

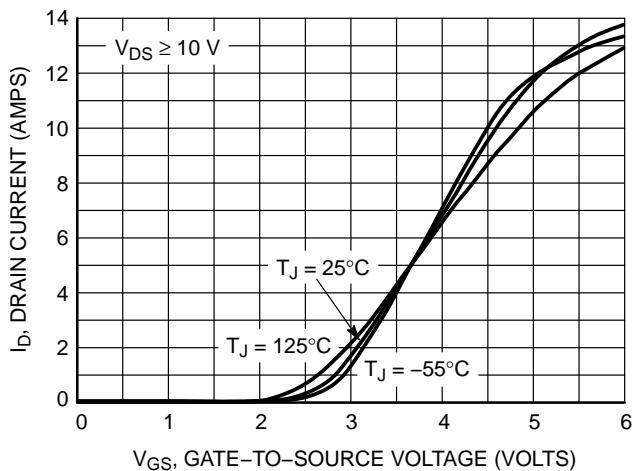


Figure 2. Transfer Characteristics

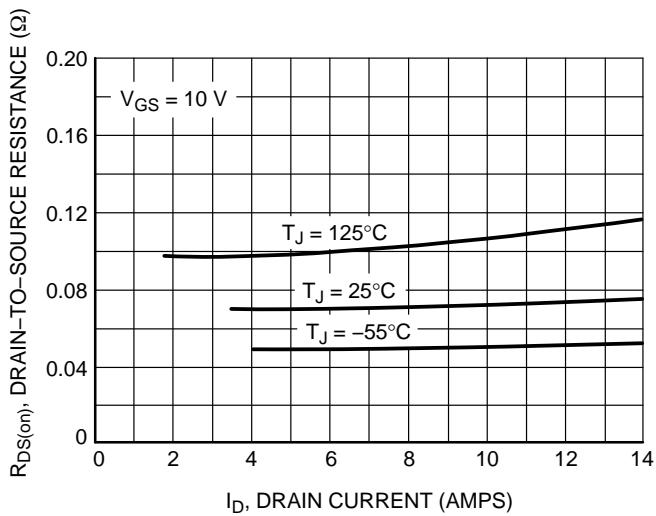


Figure 3. On-Resistance versus Drain Current and Temperature

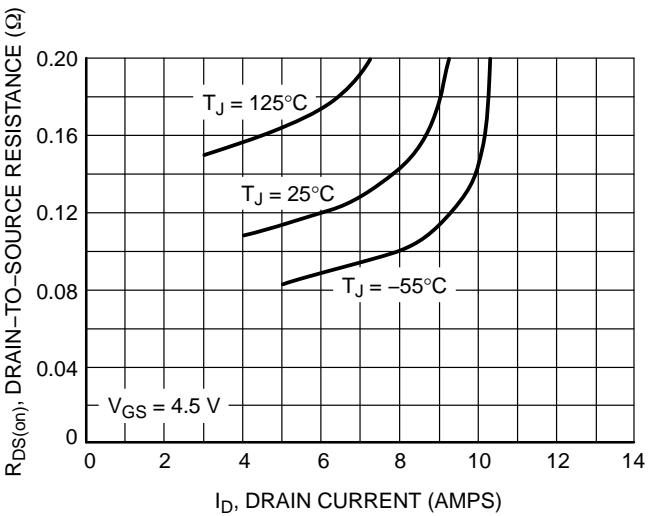


Figure 4. On-Resistance versus Drain Current and Temperature

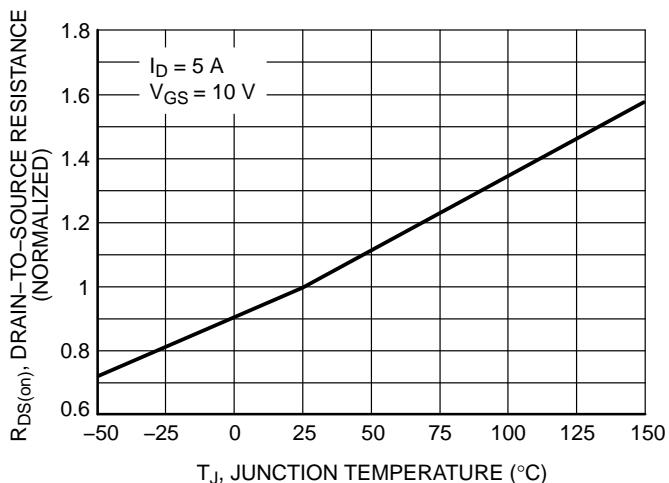


Figure 5. On-Resistance Variation with Temperature

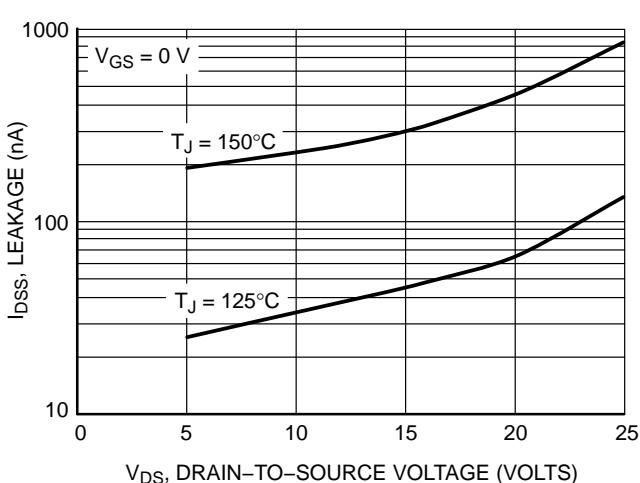


Figure 6. Drain-to-Source Leakage Current versus Voltage

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TYPICAL CHARACTERISTICS

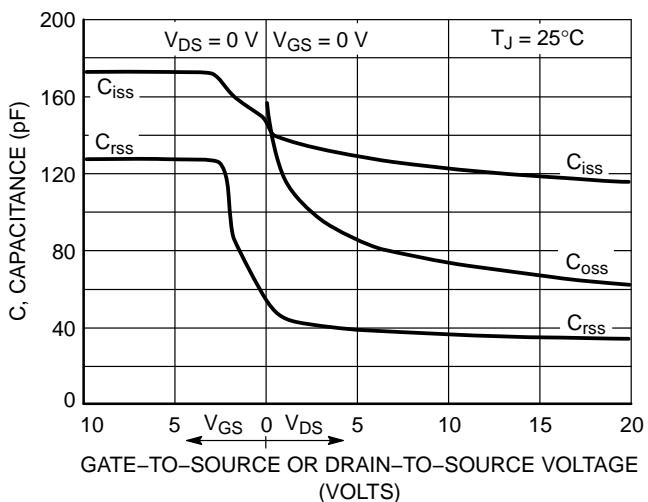


Figure 7. Capacitance Variation

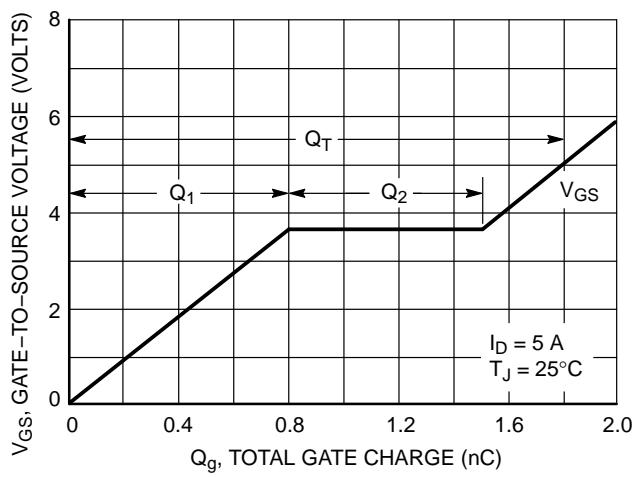


Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

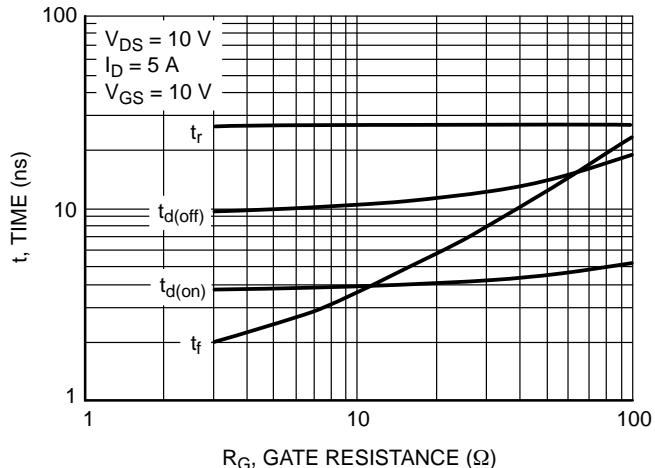


Figure 9. Resistive Switching Time Variation versus Gate Resistance

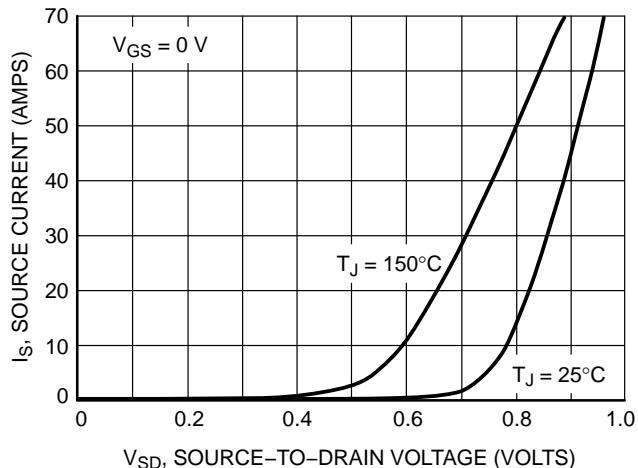


Figure 10. Diode Forward Voltage versus Current

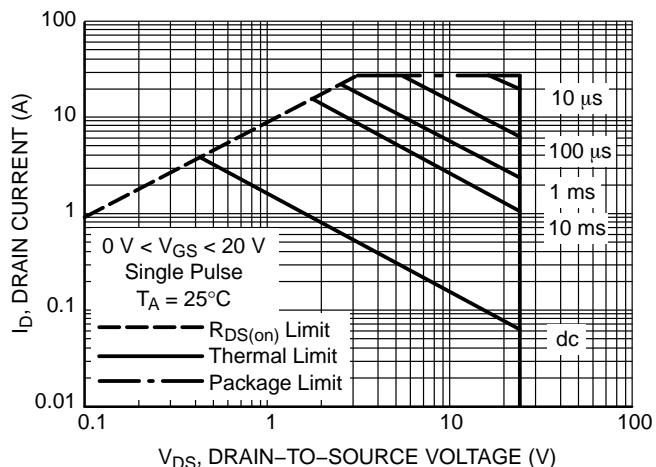


Figure 11. Maximum Rated Forward Biased Safe Operating Area

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TYPICAL CHARACTERISTICS

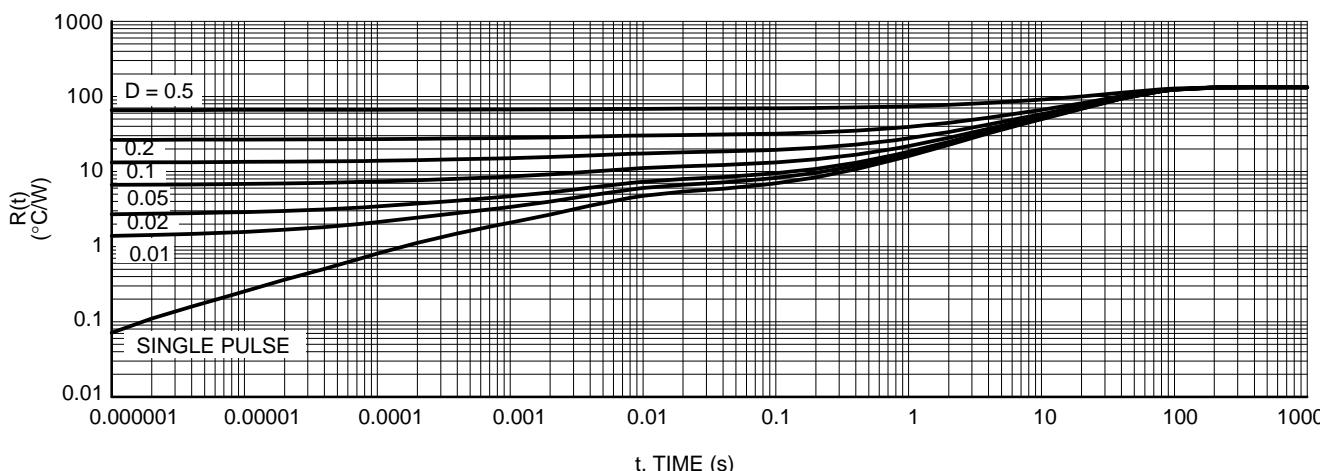


Figure 12. Thermal Response

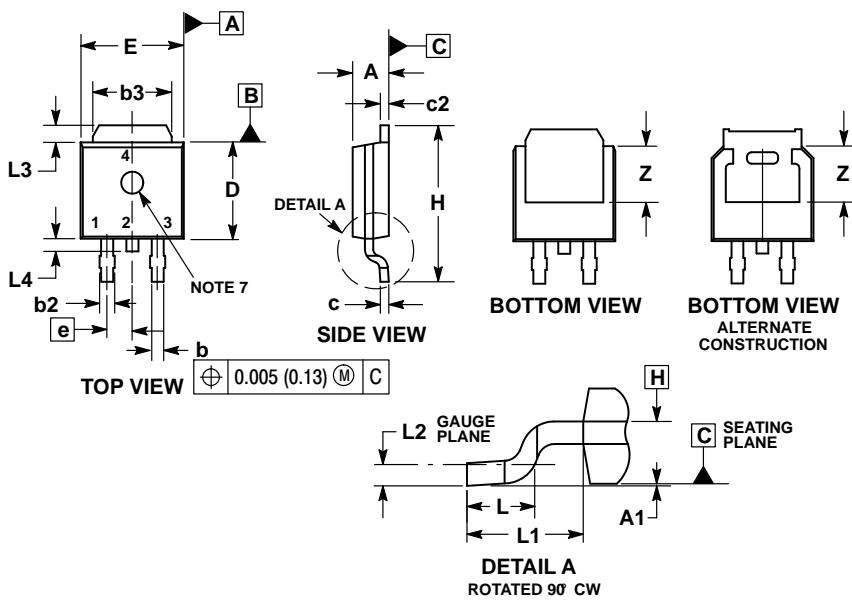
ORDERING INFORMATION

Device	Package	Shipping [†]
NTD14N03RT4G	DPAK (Pb-Free)	2500 / Tape & Reel
NVD14N03RT4G*	DPAK (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

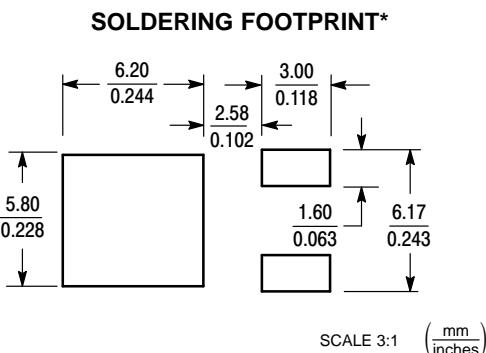
*NVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)
CASE 369C
ISSUE E

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090	BSC	2.29	BSC
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90	REF
L2	0.020	BSC	0.51	BSC
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

STYLE 2:
 PIN 1. GATE
 2. DRAIN
 3. SOURCE
 4. DRAIN



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ООО "ЛайфЭлектроникс"

"LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

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С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибуторских договоров

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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
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- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

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Конструкторский отдел помогает осуществить:

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- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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